



Interflux, bringing chemistry to electronics for over 36 years

# EDM Workshop Interflux Electronics 18-05-2021

## Low melting point solder technology for advanced processor components



## introduction to Interflux Electronics nv

Belgian company, privately owned by Mr. Daniel Werkhoven

Founded in 1985

Development and production of soldering chemicals and solder alloys

HQ and main production site located in Ghent, Belgium

7 IF sister companies worldwide

ISO9001:2015 certified



## introduction to low melting point solder alloys

### Melting Point

- solder alloy composition with a melting point between 120°C and 180°C
- 40°C-80°C lower melting point than SAC-based solder alloys (217°C-227°C)
- eutectic or non-eutectic

### Composition

- SnBi+x (Bi 35% to 58%) or SnIn+x.
- SnBi(+x) solders are more common due to lower cost in comparison with SnIn(+x).

### Generations

- **Gen1** : SnBi : Poor drop shock and thermal cycling performance
- **Gen2** : SnBiAg : improved performance over Gen1, addition of Ag
- **Gen3** : SnBi+”ductility enhancing dopands” : Further improvement over Gen2

## introduction to low melting point solder alloys

### Processability

- Current Low Melting Point soldering products are used in **reflow soldering, wave soldering, selective soldering, dip soldering and hand soldering**

### Field of application

- modern low melting point solder alloys are used in a wide range of applications : **Railway, Automotive, Lighting, ... where Tpeak does not exceed 125°C.**

## processing a low melting point alloy : process temperatures

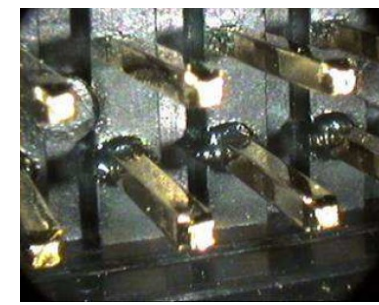
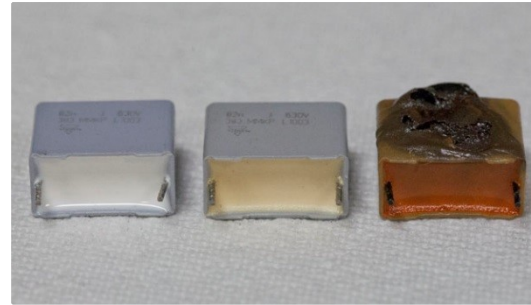
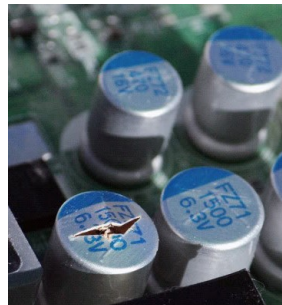
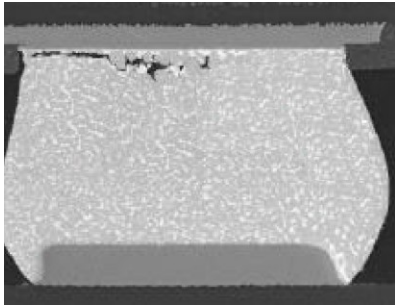
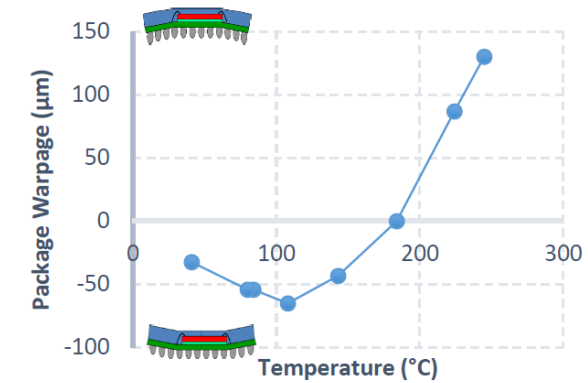
- Overview of typical temperatures used in various soldering processes

Process	T°-settings (°C) SAC Solder	T°-settings (°C) LMPA™-Q
Wave soldering	250 - 280	210-230
Selective soldering	260 - 330	230-250
<b>Reflow soldering convection</b>	<b>235 – 250 (peak)</b>	<b>190-210 (peak)</b>
Reflow soldering vapour phase	230	200
Hand soldering	320 - 400	300-350

## component damage

**Lower process temperatures lead to lower thermal and thermo-mechanical stress on temperature sensitive components**

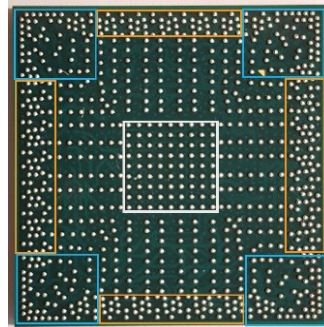
- Warping of BGA, LGA, QFN,... components
- Elco's, capacitors, LED's...
- Plastic body components
- Soldering defects : Hot-tear, HiP,...



- Lower process temperatures lead to lower defect rate and lower energy consumption

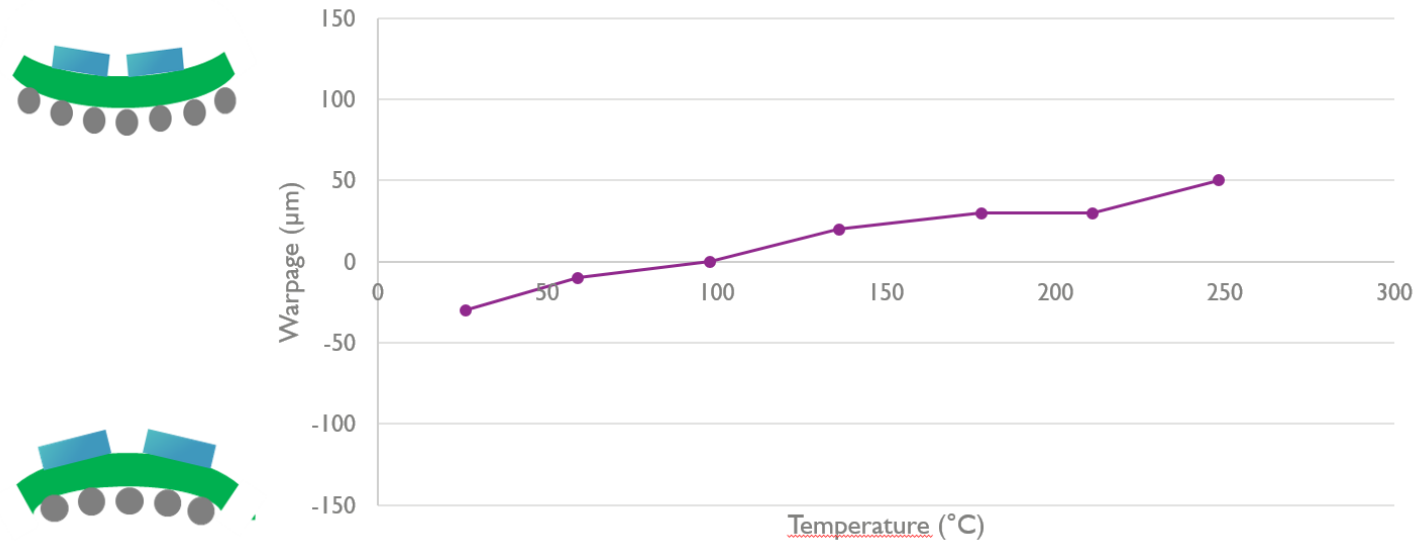
## low melting point alloy : BGA component study

- **Component warping and hot-tear analysis**
  - Advanced PC processor
  - FCBGA with 885 solder ball connections (SAC305)
  - Ball size :  $\varnothing 0,305\text{mm}$
  - Size : 24x23mm
  - **Sensitive to  $T > 200^{\circ}\text{C}$** 
    - Warping
    - Hot tear defects / HiP defects



## component warping

- **Component warping analysis**
  - 25° → 250°C
  - Concave at low temperature
  - Convex at high temperature



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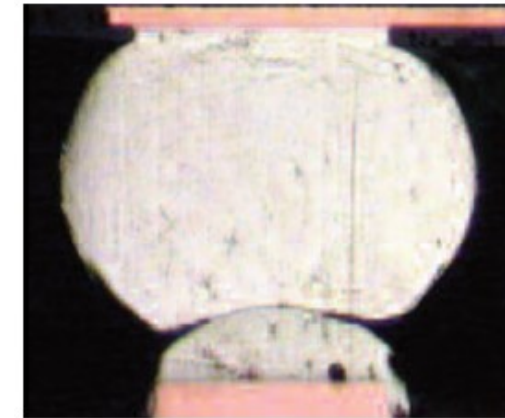
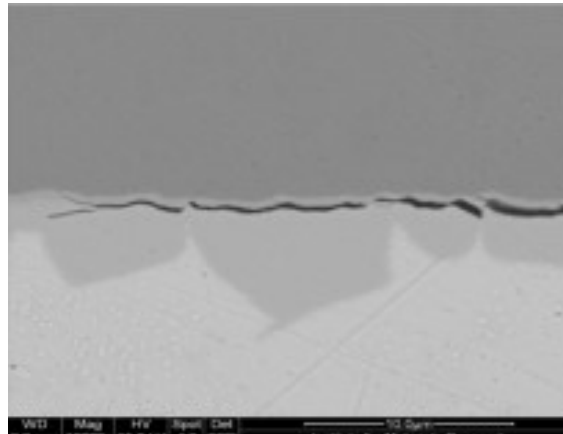
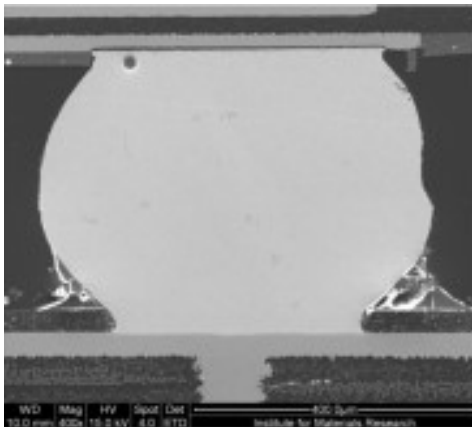
## Hot tear / HiP defect

### Hot tear defect

- Crack formation after soldering process
- Bulk solder / solder-PCB interface / solder-component interface
- **Cause**
  - CTE differences
  - Component /PCB warping
  - Solder alloy shrinkage
  - Reflow temperature

### HiP defect

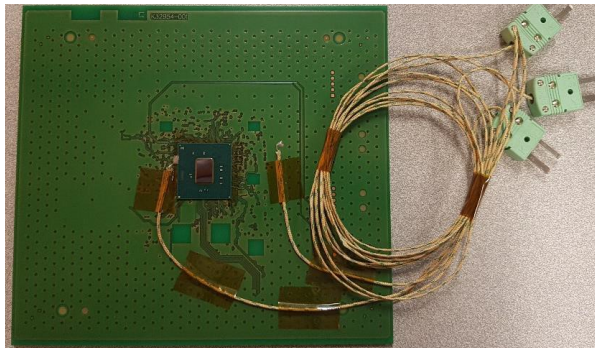
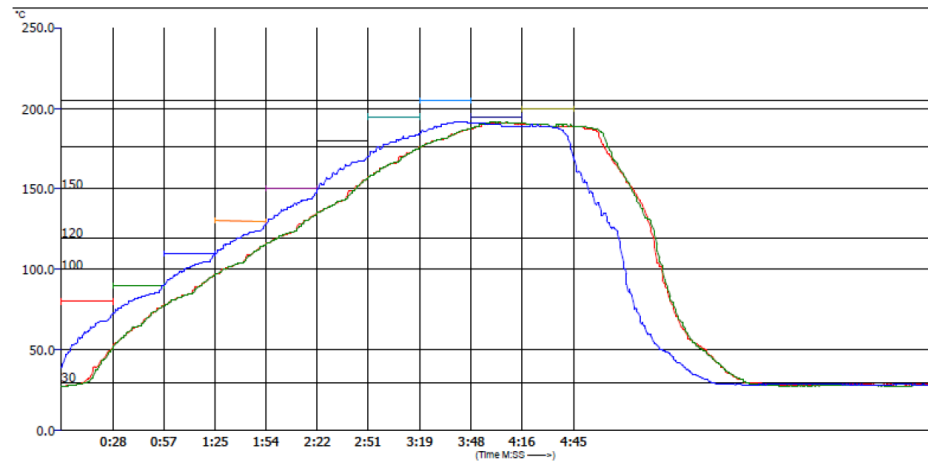
- No metallic connection
- **Cause**
  - Warping
  - Flux exhaustion
  - Reflow temperature



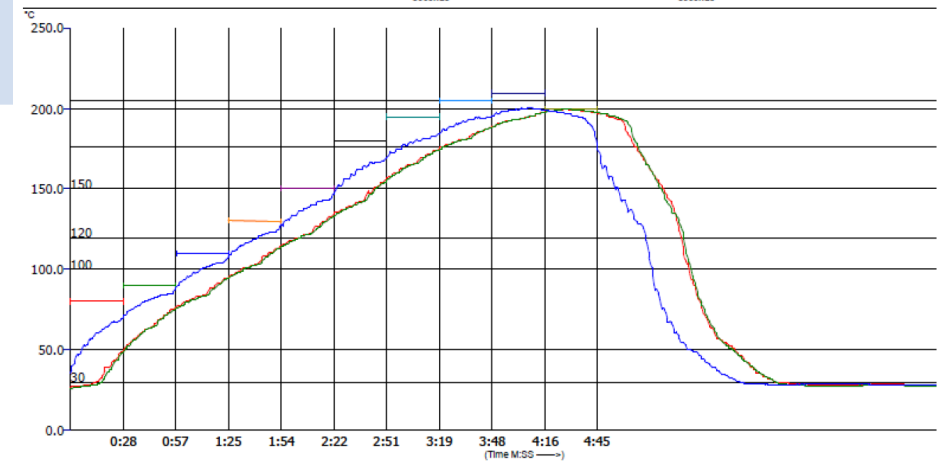
## Hot tear / HiP defect

- Soldering on FR4 OSP-Cu PCB substrate
  - Different soldering reflow profiles

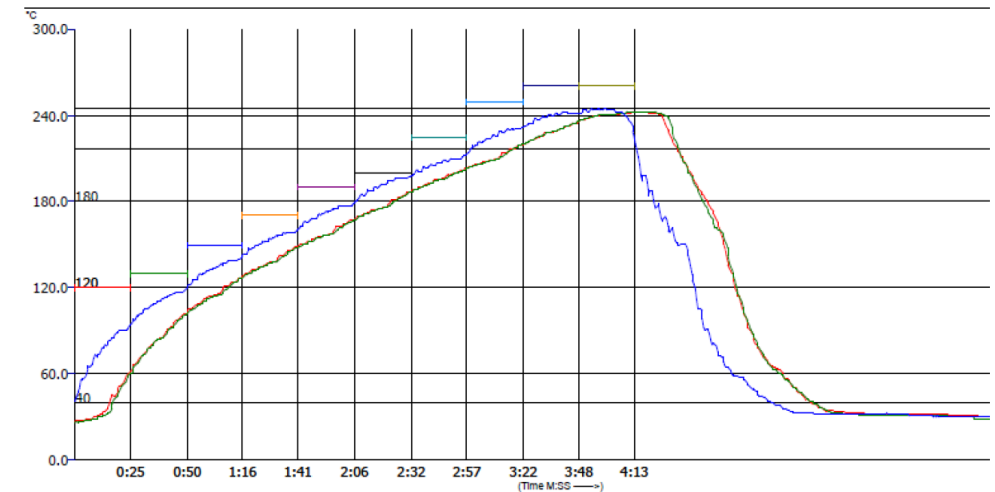
190°C "Long Peak" Profile



200°C Peak Linear Profile

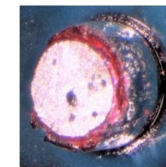
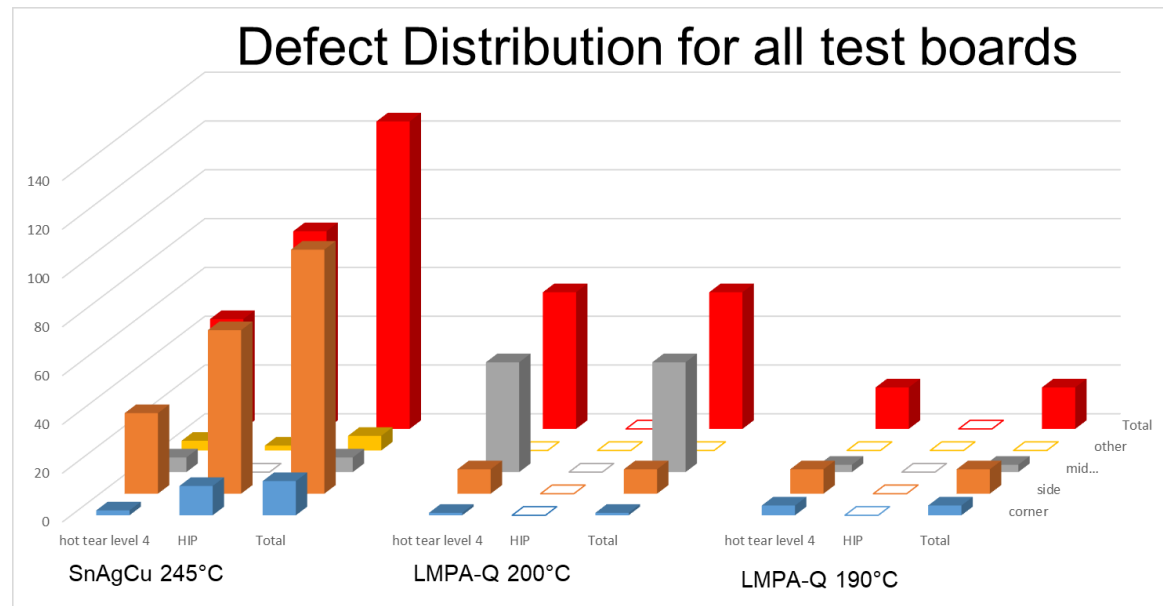


Lead-Free Linear Profile

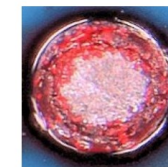


## Hot tear /HiP defect analysis

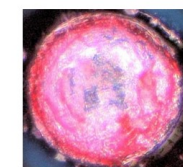
### ▪ Dye-and-pry analysis results



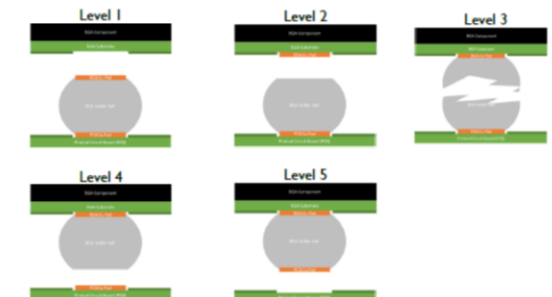
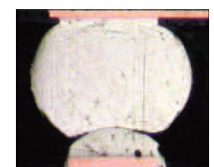
OK



Hot tear



HiP/ HoP



Fracture level 1: The Cu pad of the component is pulled out of the BGA substrate.

Fracture level 2: Fracture at the component pad to BGA ball interface.

Fracture level 3: Fracture in the bulk solder of the BGA ball.

Fracture level 4: Fracture at the BGA ball to PCB pad interface.

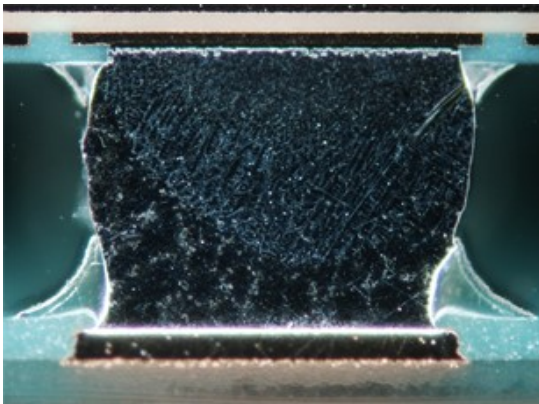
Fracture level 5: The Cu pad of the PCB is pulled out of the PCB laminate.

- Mainly hot tear “level 4” defects, and head-in pillow defects.
- Lowest failure rate obtained with LMPA™-Q, soldered at 190°C

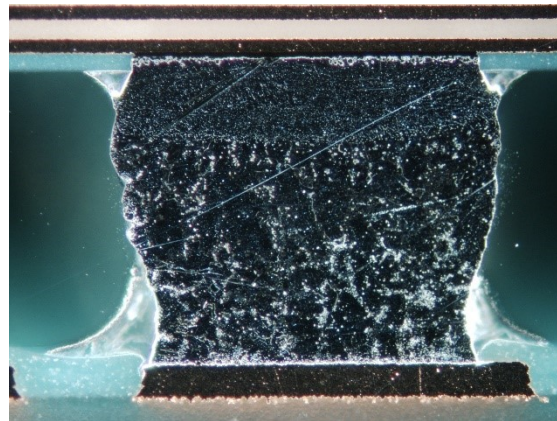
## BGA cross section

### Compatibility between Low Melting Point Solder (LMPA™-Q) and SAC BGA

- Low Melting Point solder makes a hybrid joint with SAC BGA
- Very low voiding
- Good mechanical strength



Hybrid joint – 190°C

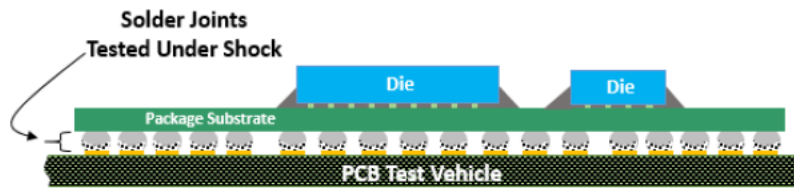


Hybrid joint – 200°C

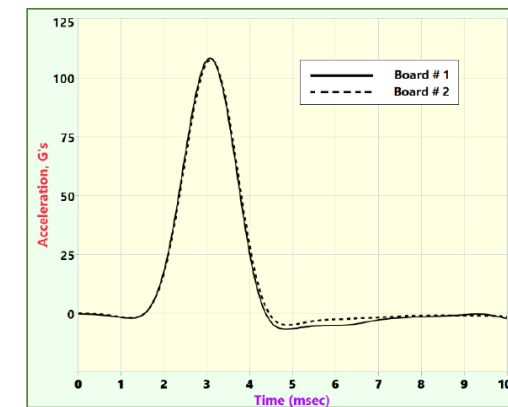
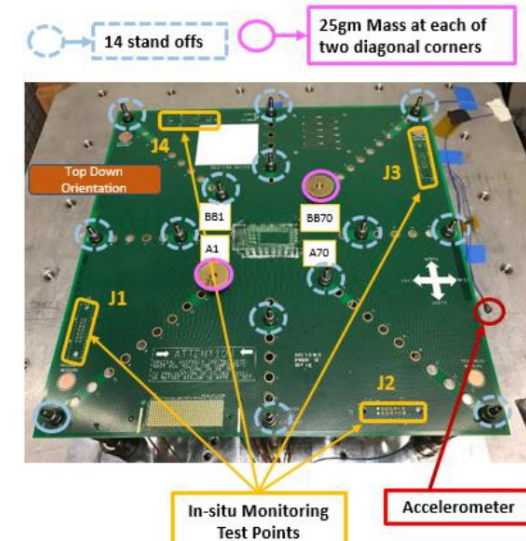
## drop shock test

### Drop shock test information

- PC Processor
- FCBGA component , size : 42mm x 28mm
- 1515 solder balls, SAC1205+Ni
- 100G – +3ms
- Extra 25gm mass at diagonal corners
- In-Situ monitoring
- SAC + SnBi-based alloys



Images and data courtesy of iNEMI

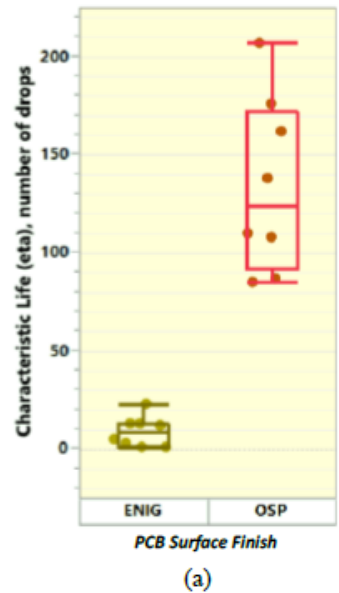




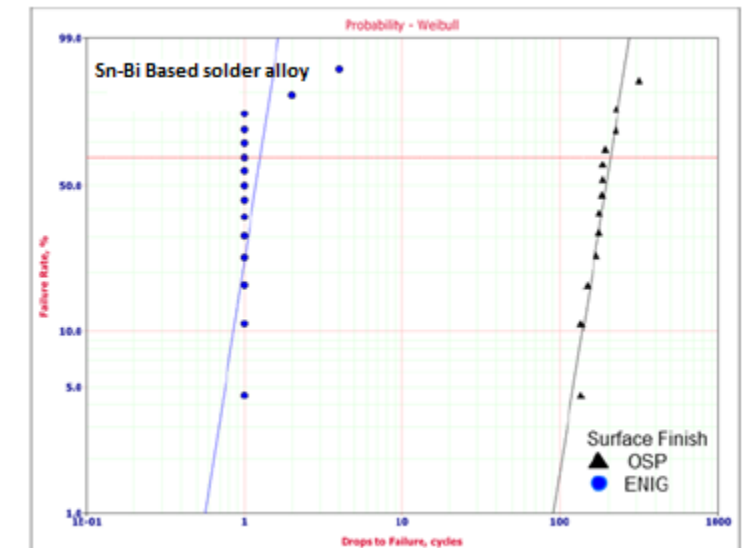
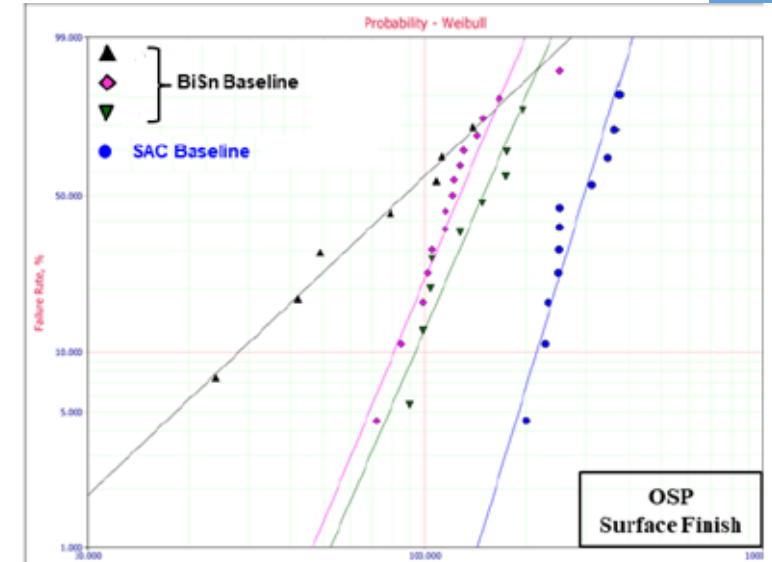
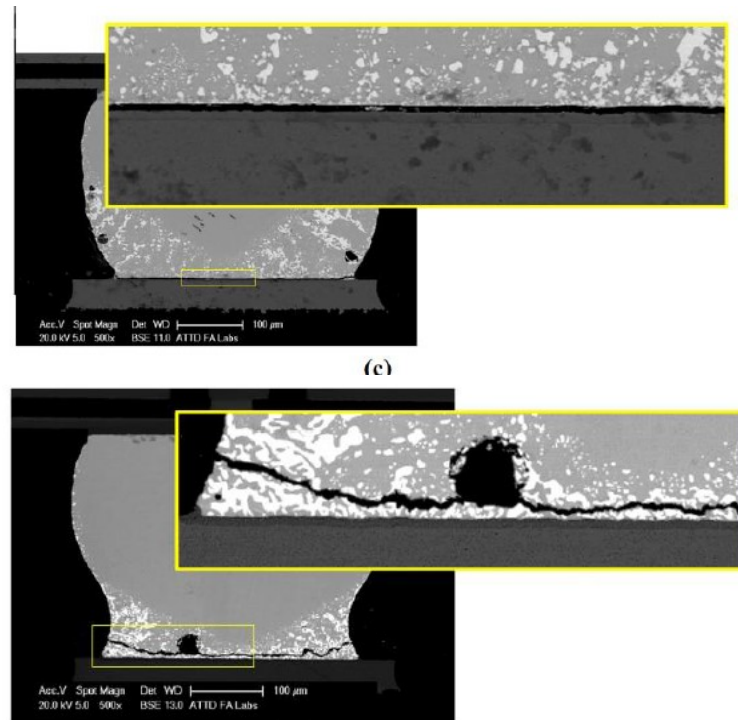
## drop shock test

### Drop shock results with hybrid solder joints

- Typically lower drop shock resistance compared to SAC
- OSP-Cu PCB finish yields better results



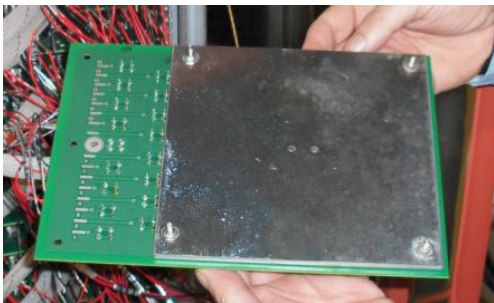
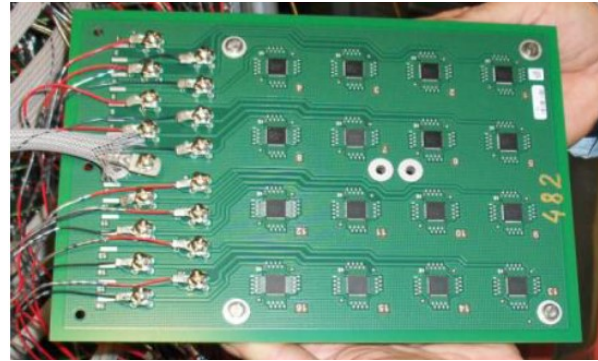
Images and data courtesy of iNEMI



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## thermal cycling

- Thermal cycling test conducted on Interflux LMPA™-Q Low Melting Point solder alloy and SAC(X) solders



### Components:

- QFN1: 9x9mm size, mold CTE = 7 ppm/°C
- QFN2: 9x9mm size, mold CTE = 15 ppm/°C

PCB: 1.6 mm thick 6-layer board

### Solder paste:

- SAC305: 3% Ag, 0.5% Cu
- SACX: 0.3% Ag, 0.7% Cu
- LMPA-Q: SnBi based

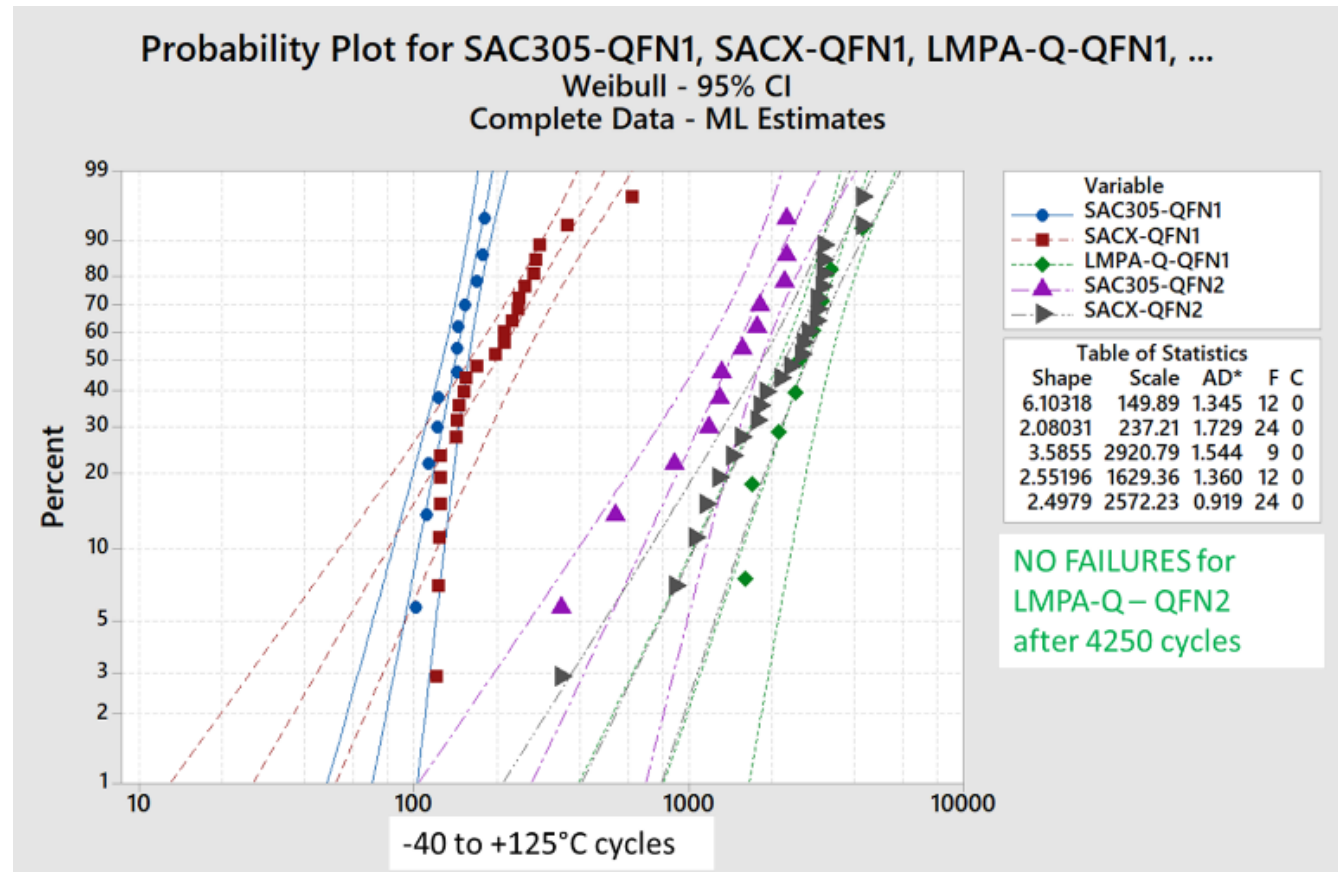
### Test condition:

- Thermal cycling: -40 to +125°C air-to-air
- ramp rate of 10°C/minute, dwell time of 10 minutes
- Test stopped after 4250 cycles

Images and data courtesy of REVUP project

## thermal cycling

- A significant increase of solder joint lifetime was obtained with the Low Melting Point solder alloy LMPA™-Q when compared to SAC(X) solder on QFN components



Images and data courtesy of REVUP project



## thermal cycling

### Components:

- 2512 resistor

### PCB: 1.6 mm thick

### Solder paste:

- SAC305: 3% Ag, 0.5% Cu
- LMPA™-Q: SnBi based
- Stencil thickness 120µm for SAC and LMPA™-Q
- Stencil thickness 80µm for LMPA™-Q

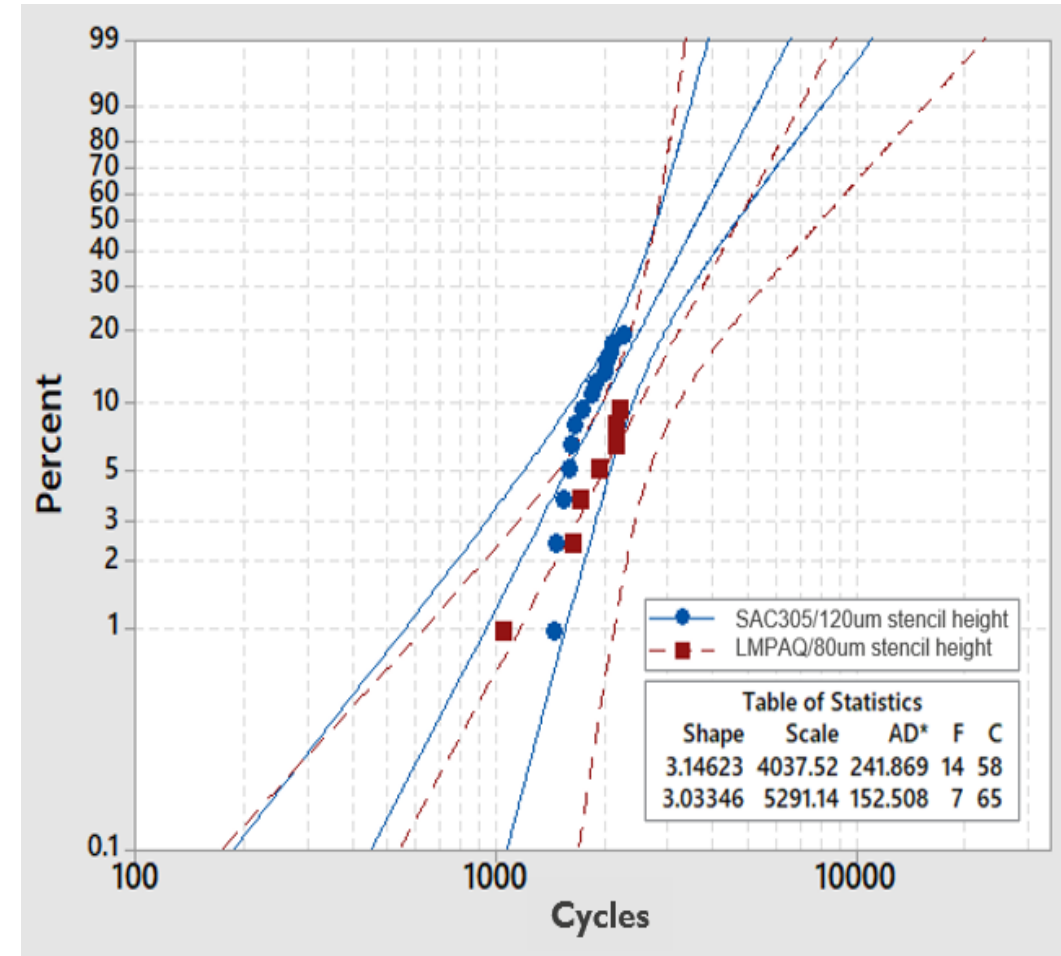
### Test condition:

- Thermal cycling: 0°C to 100°C air-to-air
- ramp rate of 10°C/minute, dwell time of 10 minutes
- Test stopped after 2800 cycles



LMPA™-Q  
outperforms SAC305,  
even with lower  
solder deposit.  
No failures were  
detected with  
LMPA™-Q with 120µm  
stencil thickness

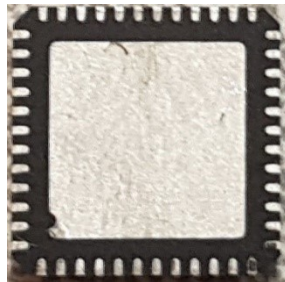
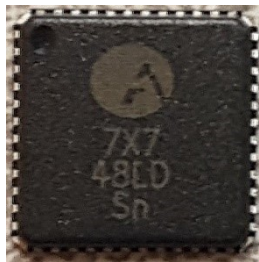
Images and data courtesy of IMEC



## void formation

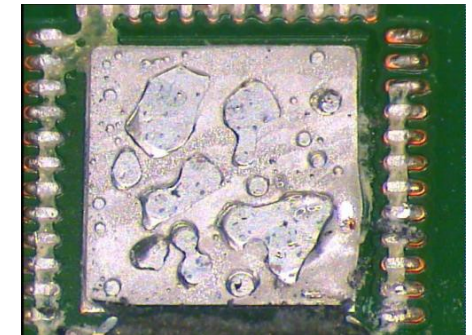
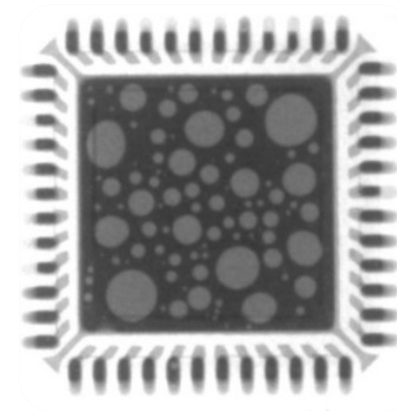
### Void formation test

- QFN component , size : 7mm x 7mm
- Sn-finished
- 100% paste print (no reduction)
  - SAC305
  - Sn42Bi57Ag1
  - LMPA™-Q
- Fr4 substrate with OSP-Cu and ENIG finish
- X-Ray analysis



### Void formation

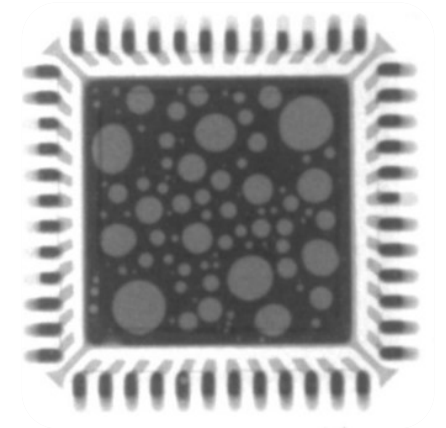
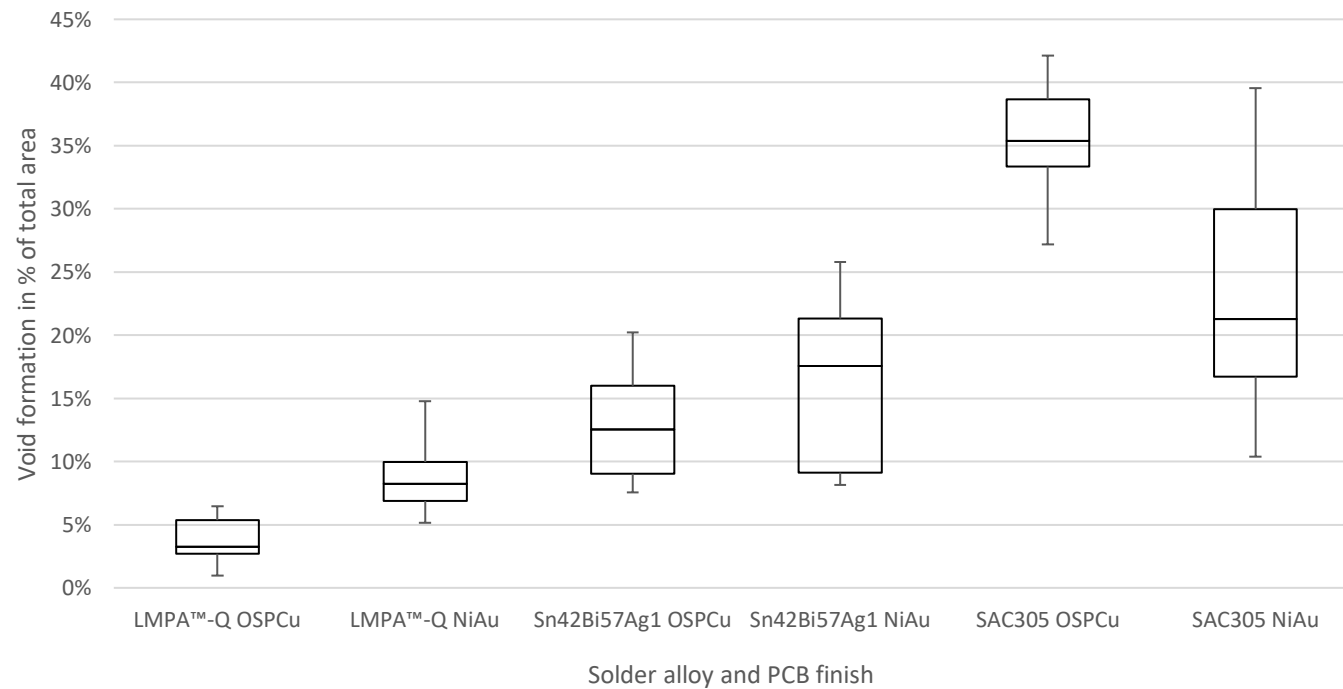
- Outgassing of flux medium
- Mitigation
  - reflow profile
  - PCB finish
  - solder alloy
  - stencil design
  - Process
    - vacuum / overpressure



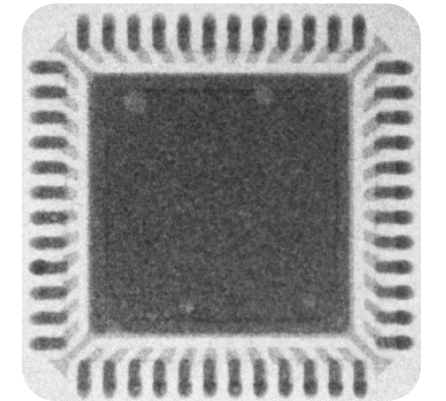
## void formation

- Lower level of voids for LMPA™-Q and Sn42Bi57Ag1 in comparison to SAC305

### Void formation QFN ground plane



SAC305 void formation



LMPA™-Q void formation



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# Thank you!

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